

# $\alpha$ -SnS (*B*29) Structure:

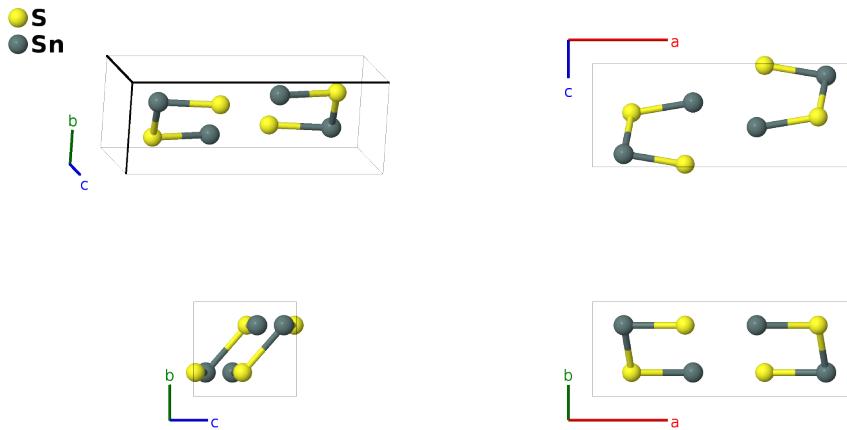
AB\_oP8\_62\_c\_c-004

This structure originally had the label AB\_oP8\_62\_c\_c.SnS. Calls to that address will be redirected here.

Cite this page as: M. J. Mehl, D. Hicks, C. Toher, O. Levy, R. M. Hanson, G. Hart, and S. Curtarolo, *The AFLOW Library of Crystallographic Prototypes: Part 1*, Comput. Mater. Sci. **136**, S1-828 (2017). doi: 10.1016/j.commatsci.2017.01.017

<https://aflow.org/p/QZKW>

[https://aflow.org/p/AB\\_oP8\\_62\\_c\\_c-004](https://aflow.org/p/AB_oP8_62_c_c-004)

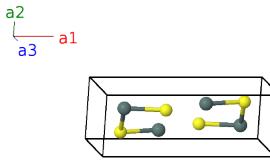


<b>Prototype</b>	SSn
<b>AFLOW prototype label</b>	AB_oP8_62_c_c-004
<b>Strukturbericht designation</b>	<i>B</i> 29
<b>ICSD</b>	24376
<b>Pearson symbol</b>	oP8
<b>Space group number</b>	62
<b>Space group symbol</b>	<i>Pnma</i>
<b>AFLOW prototype command</b>	<code>aflow --proto=AB_oP8_62_c_c-004 --params=a,b/a,c/a,x1,z1,x2,z2</code>

- This is the room temperature structure of SnS. Above 875K (Villars, 2018) it transforms into the  $\beta$ -SnS structure.
- (Parthé, 1993) prefers the *B*16 designation for this structure, as SnS and GeS are very similar.
- FeAs (*B*14), GeS (*B*16), FeB (*B*27), SnS (*B*29), MnP (*B*31), and  $\eta$ -NiSi (*B*<sub>d</sub>) all share the same AFLOW label, AB\_oP8\_62\_c\_c. The structures are generated by the same symmetry operations with different sets of parameters (`--params`) specified in their corresponding CIF files.

Simple Orthorhombic primitive vectors

$$\begin{aligned}\mathbf{a}_1 &= a \hat{\mathbf{x}} \\ \mathbf{a}_2 &= b \hat{\mathbf{y}} \\ \mathbf{a}_3 &= c \hat{\mathbf{z}}\end{aligned}$$



## Basis vectors

	Lattice coordinates	=	Cartesian coordinates	Wyckoff position	Atom type
$\mathbf{B}_1$	$x_1 \mathbf{a}_1 + \frac{1}{4} \mathbf{a}_2 + z_1 \mathbf{a}_3$	=	$a x_1 \hat{\mathbf{x}} + \frac{1}{4} b \hat{\mathbf{y}} + c z_1 \hat{\mathbf{z}}$	(4c)	S I
$\mathbf{B}_2$	$-(x_1 - \frac{1}{2}) \mathbf{a}_1 + \frac{3}{4} \mathbf{a}_2 + (z_1 + \frac{1}{2}) \mathbf{a}_3$	=	$-a(x_1 - \frac{1}{2}) \hat{\mathbf{x}} + \frac{3}{4} b \hat{\mathbf{y}} + c(z_1 + \frac{1}{2}) \hat{\mathbf{z}}$	(4c)	S I
$\mathbf{B}_3$	$-x_1 \mathbf{a}_1 + \frac{3}{4} \mathbf{a}_2 - z_1 \mathbf{a}_3$	=	$-a x_1 \hat{\mathbf{x}} + \frac{3}{4} b \hat{\mathbf{y}} - c z_1 \hat{\mathbf{z}}$	(4c)	S I
$\mathbf{B}_4$	$(x_1 + \frac{1}{2}) \mathbf{a}_1 + \frac{1}{4} \mathbf{a}_2 - (z_1 - \frac{1}{2}) \mathbf{a}_3$	=	$a(x_1 + \frac{1}{2}) \hat{\mathbf{x}} + \frac{1}{4} b \hat{\mathbf{y}} - c(z_1 - \frac{1}{2}) \hat{\mathbf{z}}$	(4c)	S I
$\mathbf{B}_5$	$x_2 \mathbf{a}_1 + \frac{1}{4} \mathbf{a}_2 + z_2 \mathbf{a}_3$	=	$a x_2 \hat{\mathbf{x}} + \frac{1}{4} b \hat{\mathbf{y}} + c z_2 \hat{\mathbf{z}}$	(4c)	Sn I
$\mathbf{B}_6$	$-(x_2 - \frac{1}{2}) \mathbf{a}_1 + \frac{3}{4} \mathbf{a}_2 + (z_2 + \frac{1}{2}) \mathbf{a}_3$	=	$-a(x_2 - \frac{1}{2}) \hat{\mathbf{x}} + \frac{3}{4} b \hat{\mathbf{y}} + c(z_2 + \frac{1}{2}) \hat{\mathbf{z}}$	(4c)	Sn I
$\mathbf{B}_7$	$-x_2 \mathbf{a}_1 + \frac{3}{4} \mathbf{a}_2 - z_2 \mathbf{a}_3$	=	$-a x_2 \hat{\mathbf{x}} + \frac{3}{4} b \hat{\mathbf{y}} - c z_2 \hat{\mathbf{z}}$	(4c)	Sn I
$\mathbf{B}_8$	$(x_2 + \frac{1}{2}) \mathbf{a}_1 + \frac{1}{4} \mathbf{a}_2 - (z_2 - \frac{1}{2}) \mathbf{a}_3$	=	$a(x_2 + \frac{1}{2}) \hat{\mathbf{x}} + \frac{1}{4} b \hat{\mathbf{y}} - c(z_2 - \frac{1}{2}) \hat{\mathbf{z}}$	(4c)	Sn I

## References

- [1] S. D. Buchchia, J.-C. Jumas, and M. Maurin, *Contribution à l'étude de composés sulfurés d'étain(II): affinement de la structure de SnS*, Acta Crystallogr. Sect. B **37**, 1903–1905 (1981), doi:10.1107/S0567740881007528.
- [2] P. Villars, H. Okamoto, and K. Cenzual, eds., *ASM Alloy Phase Diagram Database* (ASM International, 2018), chap. Sulfur-Tin Binary Phase Diagram (1990 Sharma R.C.). Copyright ©2006-2018 ASM International.
- [3] E. Parthé, L. Gelato, B. Chabot, M. Penso, K. Cenzula, and R. Gladyshevskii, *Standardized Data and Crystal Chemical Characterization of Inorganic Structure Types, Gmelin Handbook of Inorganic and Organometallic Chemistry*, vol. 2 (Springer-Verlag, Berlin, Heidelberg, 1993), 8 edn., doi:10.1007/978-3-662-02909-1\_3.